# NSN 5961-01-314-3166

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# Inclosure Material:

Metal

**Overall Length:** 

1.253 inches

# **Overall Height:**

0.300 inches

# **Overall Width:**

0.700 inches

# **Mounting Facility Quantity:**

2

#### Internal Configuration:

Junction contact

#### Joint Electronic Device Engineering Council/jedec/case Outline Designation:

#### To-66

Electrode Internally-electrically Connected To Case:

Collector

#### Mounting Method:

Unthreaded hole

#### Features Provided:

Hermetically sealed case

#### Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

60.0 collector to base voltage/static/emitter open and 60.0 collector to emitter voltage/static/base open and 5.0 breakdown voltage,

emitter-to-base, collector open

# **Current Rating Per Characteristic:**

10.00 amperes source cutoff current

#### **Power Rating Per Characteristic:**

25.0 watts small-signal input power, common-collector preset

#### **Transfer Ratio:**

20.0 static forward current transfer ratio, common-emitter

# Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

# **Special Features:**

Junction pattern arrangement: pnp

# **Terminal Type And Quantity:**

2 pin and 1 case

Shelf Life:

N/a

# Unit Of Measure:

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#### Demilitarization:

No

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